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| 1  | MSH2 and MSH6 in mismatch repair system  |
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| 2  | account for soybean (Glycine max (L.) Merr.)   |
| 3  | tolerance to cadmium toxicity by determining   |
| 4  | DNA damage response  |
| 5  | Olena Zhaod Hatana Manaî 1 Vanli Dud Hilany I. Dagarad Zhivin Mud Can  |
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| 22 |  |

23 Abstract

Our aim was to investigate DNA mismatch repair (MMR) genes regulating 24 cadmium tolerance in two soybean cultivars. Cultivars Liaodou 10 (LD10, Cd-25 sensitive) and Shennong 20 (SN20, Cd-tolerant) seedlings were grown 26 hydroponically on Murashige & Skoog (MS) media containing 0-2.5 mg L<sup>-1</sup> Cd 27 for 4 days. Cd stress induced less random amplified polymorphism DNA (RAPD) 28 polymorphism in LD10 than in SN20 roots, causing G1/S arrest in LD10 and 29 G2/M arrest in SN20 roots. Virus-induced gene silencing (VIGS) of MLH1 in 30 31 LD10-TRV-MLH1 plantlets showed markedly diminished G1/S arrest, but enhanced root length/area under Cd stress. However, an increase in G1/S 32 arrest and reduction of G2/M arrest occurred in SN20-TRV-MSH2 and SN20-33 34 TRV-MSH6 plantlets with decreased root length/area under Cd stress. Taken together, we conclude that low expression of MSH2 and MSH6, involved in the 35 G2/M arrest, results in Cd-induced DNA damage recognition bypassing the 36 37 MMR system to activate G1/S arrest with the assistance of MLH1. This then 38 leads to repressed root growth in LD10, explaining the inter-varietal difference in Cd tolerance in soybean. 39

Keywords: Cd toxicology, Cell cycle arrest, DNA damage, DNA mismatch
repair, Root growth repression, Soybean (*Glycine max* (L.) Merr.)

42

43 Introduction

Cadmium (Cd) is one of the most toxic heavy metal contaminants. A large 44 amount of Cd has been released into ecosystems mostly through 45 anthropogenic activities, such as lead-zinc mining, nonferrous metal smelting 46 and phosphate fertilizer utilization.<sup>1</sup> Due to its long half-life of 18-30 years in 47 biota, Cd can persist in ecosystems for a long time. Since Cd is readily 48 absorbed and accumulated in organisms, Cd bioaccumulation and 49 biomagnification throughout the food chain induce widespread genetic toxicity 50 or cytotoxicity in cells.<sup>2,3</sup> It is well known that Cd stress can directly induce a 51 wide range of injury symptoms in plants, such as the inhibition of photosynthesis, 52 causing oxidative stress and cell cycle modulation or apoptosis.<sup>4</sup> Therefore, 53 54 research into the molecular mechanisms of Cd stress in plants is an important topic in environmental and agricultural science. 55

It has been shown that Cd stress can directly interact with the hydrogen 56 bonds in the bases and base pairs of DNA, leading to a variety of reversible 57 and/or irreversible DNA lesions in plants, such as base-base mismatches, 58 insertion/deletion loops, DNA adducts, DNA chain cross linking and breaks.<sup>5-7</sup> 59 Cd stress can induce the production of oxygen radicals and regulate gene 60 expression through changes in the DNA structure or a destruction of the DNA 61 repair system, which indirectly results in DNA damage.<sup>8</sup> DNA damage is sensed 62 and repaired through a series of signal transduction pathways which are known 63 as DNA damage response (DDR). These maintain high fidelity of genetic 64

information, and the main DNA damage repair mechanisms include base 65 excision repair (BER), nucleotide excision repair (NER), mismatch repair, 66 (MMR), non-homologous end joining (NHEJ) and homologous recombination 67 (HR) in eukaryotes. Damaged DNA is recognized by cell cycle checkpoints, 68 then cell cycle progression is slowed down or arrested to provide the cells with 69 sufficient time to repair DNA damage or undergo cell death.<sup>9</sup> There are three 70 checkpoints in the eukaryotic cell cycle: the G1/S phase checkpoint preventing 71 the damaged DNA or mutant cells entering into S phase; the S phase 72 checkpoint arresting the replication of damaged DNA; and the G2/M checkpoint 73 arresting the cells with damaged DNA from entering mitosis. Cell cycle 74 checkpoint control is a complex molecular mechanism involving multiple 75 signaling pathways.<sup>10</sup> ATM and ATR kinases are sensors for various types of 76 DNA damage, and activate signal transduction pathways regulating the DNA 77 damage checkpoints.<sup>11</sup> For example, in animal cells, ATM/ATR activates the 78 phosphorylation of p53-P21 proteins, which inhibit the activities of CDK2 and 79 CDK4, and participate in the G1/S or G2/M arrest in response to DNA damage. 80 Furthermore, in animal cells G2/M arrest induced by DNA damage is regulated 81 by ATM/ATR-Chk2/Chk1 signaling pathways, including the protein activities of 82 cell division cycle (Cdc25), WEE1, CDK1, BRCA1, RAD51 and Cyclin B. <sup>12,13</sup> 83 The MMR system is a key DNA repair pathway, and is involved in a wide 84 range of important cellular processes such as sensing and correcting DNA 85

86 damage, governing cell cycle progression, confirming fidelity of DNA replication,

and maintaining genomic stability in the presence of structurally anomalous 87 nucleotide lesions under different stresses.<sup>14,15</sup> In plants, the functions of the 88 MMR system are through a complex interaction among MutS and MultL protein 89 families.<sup>16,17</sup> The MMR proteins MSH1-MSH7 are from the MutS family, while 90 MLH1, MLH3, PMS1 and PMS2 belong to the MutL family.<sup>18,19</sup> DNA errors 91 92 involving base-base mismatches and single (1-2 bases) insertion/deletion loops are recognized by heterodimer complexes known as MutSa (MSH2-MSH6) 93 and MutSy (MSH2-MSH7), whereas 2-12 base insertion/deletion loops are 94 recognized by MutSβ (MSH2–MSH3).<sup>20,21</sup> Also, the protein complex known as 95 MutLs (MutL $\alpha$  and MutL $\beta$ ) participate in MMR progression.<sup>22</sup> In fact, the MutL $\alpha$ 96 (MLH1-PSM1) can bind to MutS $\alpha$  or MutS $\beta$  to deliver the DNA damage signal 97 98 through PCNA and/or RFC pathway, and activate the MMR reaction to repair DNA base mismatch damage.<sup>23,24</sup> In mammals, DNA damage recognized by 99 MMR proteins can activate the G2/M cell cycle checkpoint. For example, 100 hMSH2 and hMLH1 modulate G2/M phase arrest by activating the 101 hMSH2/hMLH1-BRCA1-ATR-CHk1 pathway in the HCC1937 human cancer 102 cell line under 6-Mercaptopurine (6-TG) stress.<sup>25</sup> hMLH1 is necessary for 103 activating the ATM-dependent DNA damage response in the HCT116 human 104 cancer cell line under selenium stress.<sup>26</sup> In plants, MSH2 had been shown to 105 play an important role in regulation of cell cycle progression in Arabidopsis 106 seedlings after UV-B treatment,<sup>16</sup> and MSH2 and MSH6 mediated Cd-induced 107 G2/M checkpoint arrest through the MutSα-ATR-WEE1 pathway in Arabidopsis 108

109 seedling roots.<sup>27</sup>

Previous research showed that Cd stress-induced G1/S and G2/M phase 110 arrest was linked with DNA damage and decreased level of cyclin B1 mRNA in 111 suspension culture soybean cells.<sup>28</sup> DNA damage tolerance determines 112 whether cells maintain the complete DNA synthesis process to sustain plant 113 growth or enter the cell death process,<sup>29</sup> and this may play an important role in 114 soybean Cd stress tolerance. However, little is known about the roles of MMR 115 proteins in Cd-induced cell cycle arrest and Cd tolerance in soybean seedlings. 116 117 In this study, two soybean cultivars, LD10 and SN20, with contrasting Cd sensitivity were used to (1) determine the levels of DNA damage in soybean 118 seedling root tips under Cd stress by RAPD analysis; (2) measure cell cycle 119 120 progression in response to Cd stress in soybean seedling roots by flow cytometry method (FCM) and qRT-PCR analyses; and (3) evaluate the potential 121 roles of MMR genes in Cd-induced cell cycle arrest and Cd tolerance in seedling 122 roots of soybean in which virus-induced gene silencing (VIGS) was used to 123 silence three MMR genes: TRV-MLH1, TRV-MSH2 and TRV-MSH6. 124

125 Materials and methods

## 126 Materials, growth and treatment conditions

Soybean (*Glycine max* L.) Merr.) seeds used in this study were harvested
on Oct. 3, 2018 from the experimental station of the Soybean Institute (41°82'N,
123°57'E), College of Agriculture, Shenyang Agricultural University, Liaoning,
PR China (Table S1). The pods were dried naturally and stored at 4 °C.

Soybean seeds were sterilized using chlorine gas (made by mixing 4 mL 12 M HCl and 100 mL 5.25% hypochlorite) in a glass desiccator for 8-10 h. To investigate the effect of Cd stress on soybean seed germination, sterilized seeds were sown in a 90 mm culture dish onto gauze saturated with a Cd solution (0, 0.25, 0.5, 2.5 mg·L<sup>-1</sup> CdCl<sub>2</sub>·2H<sub>2</sub>O). The seed germination efficiency was measured at 28 ± 1 °C in darkness after 2 days.

To avoid the effects from heterogeneity in germination amongst seeds from 137 the same batch, sterilized seeds were germinated on gauze soaked in distilled 138 139 water and checked for uniformity of germination. The seeds were kept for approximately 2 days at 28  $\pm$  1 °C in darkness, until the hypocotyls were 1-1.5 140 cm. The uniformly germinated soybean seeds were selected and transferred 141 142 into Murashige & Skoog (MS, Caisson, USA) liquid medium with different Cd concentrations of 0 (control), 0.25, 0.5, 2.5 mg·L<sup>-1</sup> in the form of CdCl<sub>2</sub>·2H<sub>2</sub>O of 143 analytical grade with purity 99.5% (PR China), and incubated for 4 days at 28 144 145 ±1 °C with a light regime of 16 h light / 8 h dark. The Cd solution was changed every other day. Before harvesting, the roots were rinsed three times with sterile 146 water and scanned using a WinRHIZO Pro 2012b root scanning image analysis 147 system (Regent Instruments, Inc., Quebec, Canada) to measure total root 148 length/area. Root length reduction (%) = (root length of the control seedling -149 root length of Cd treated seedling) / root length of the control seedling x 100%. 150 The fresh weight of soybean seedling was quickly measured, and then about 1 151 cm long root tips were cut and flash-frozen in liquid nitrogen prior to storage at 152

-80 °C. Soybean seedlings were oven-dried at 105 °C for 30 min and then at
85 °C until a constant weight was achieved. All treatments and analyses were
repeated in at least three independent replicates.

156

## **DNA extraction and RAPD analysis**

Total genomic DNA was extracted and purified using a Plant Genomic DNA 157 Isolation Kit (Tiangen, Beijing, PR China) from about 100 mg of fresh root tips 158 frozen at -80 °C. The RAPD analysis was performed using 2 primers (primers 159 2 and 6) screened from 12 random primers as described previously (Table 160 S2).<sup>30</sup> Following PCR amplification, polymorphism frequency of RAPDs, was 161 assessed by polyacrylamide gel electrophoresis (PAGE) gel electrophoresis, 162 and was calculated according to Wang et al.<sup>7</sup> The genome template stability 163 164 (GTS) was calculated using the equation:  $GTS = (1 - a/n) \times 100\%$ , where a and n represent the average frequency of RAPDs polymorphism in Cd treated and 165 control roots, respectively. For all treatments, bands were considered 166 reproducible, and were used for polymorphism analysis when detected 167 simultaneously in at least two experimental replicates. 168

## 169 FCM analysis of cell cycle progression in soybean seeding root tips

Nuclei were extracted using chopping buffer<sup>7</sup> from approximately 0.1 g of fresh soybean seedling root tips (about 1 cm long). The root tips were chopped into 0.5 mm strips using a single-edged razorblade in a glass Petri dish (diameter, 5 cm) with 2 mL ice cold chopping buffer. After 5 minutes in an ice bath, the mixture was filtered through a 30 µm nylon mesh twice to remove cell

debris. 1 mL of mixture was transferred into a 1.5 mL centrifuge tube, and 175 incubated with 15 µg·L<sup>-1</sup> RNase A in a water bath at 37 °C for 2 h. The mixture 176 was stained with 50 µg·L<sup>-1</sup> propidium iodide (PI, Beyotime, PR China) at 4 °C 177 for 0.5-1 h. The ploidy level of the control and Cd-treated samples was analyzed 178 using a Guava easyCyte 6-2 L flow cytometer (EMD Millipore, USA) equipped 179 with a 488 nm laser. Fluorescence intensity was analyzed in the Red-B-HLin 180 channel with more than 5000 nuclei measured for each sample, and three 181 independent replicates were performed for each sample. Gates (Figures S3 182 and S9) were determined empirically and ploidy distribution was analyzed using 183 Flowjo 7.6.1 win 64 software (BD Biosciences, San Jose, CA). 184

## 185 RNA extraction, first-strand cDNA synthesis and qRT-PCR analysis

Total RNA was isolated and purified using a Plant Total RNA Isolation Kit (Qiagen, Hilden, Germany) from about 100 mg of fresh root tips frozen at -80 °C according to the manufacturer's manual. First-strand cDNA was synthesized from 1 µg of total RNA using a TransScript® All-in-One First-Strand cDNA Synthesis SuperMix (TransScript, Beijing, PR China) in a final volume of 20 µL, and stored at -20 °C.

The reaction mixture (1  $\mu$ L) was used for qRT-PCR in a 20  $\mu$ L reaction volume using TransScript<sup>®</sup> Top Green qPCR SuperMix (TransScript, Beijing, PR China). The soybean *Tubulin A*(NM\_001250372) or *Actin* (NM\_001289231) gene was used for signal normalization. The primers used for amplifying specific genes were designed using the online QuantPrime software (http://quantprime.mpimp-golm.mpg.de/) and are listed in Table S2. The qRT-PCR products were confirmed as the correct amplification products by analysis on 2% (w/v) agarose gels and sequencing. The operational formula  $2^{-\Delta\Delta^{Ct}}$  was used to calculate relative expression levels of the selected genes between different treatments.<sup>31</sup> The qRT-PCR experiments and analyses were performed with three biological replications, and each biological replication was measured in three technical replications.

## 204 **Construction of VIGS-induced gene silencing plasmids**

TRV1 and TRV2 plasmids were used to produce amiRNAs (artificial 205 miRNAs) for gene silencing via VIGS technology.<sup>32</sup> All the constructs used for 206 VIGS-induced gene silencing were assembled into the TRV2 plasmid. Gene 207 fragments of PDS (XM\_028355994), MLH1 (XM\_003522549), MSH2 208 (XM 003549757) and MSH6 (XM 006604676) were amplified by PCR from 209 cDNA of LD10 and SN20 leaves. The specific primers used in PCR were 210 designed with BamH I and Xho I restriction sites in the forward and reverse 211 primers, respectively (listed in Table S2). The sizes of PCR products were 212 confirmed by 1.5% agarose gel electrophoresis, and then validated by 213 sequencing. The validated fragments were inserted into the TRV2 plasmid 214 between the BamH I and Xho I restriction sites to construct the -TRV-PDS, -215 TRV-MLH1, -TRV-MSH2 and -TRV-MSH6 VIGS-induced gene silencing 216 plasmids (as shown in Figure S4). 217

218 Soybean sprout vacuum-infiltration for VIGS

A sprout vacuum-infiltration method<sup>33</sup> was used to develop VIGS-induced 219 gene silencing lines of LD10 including LD10-TRV2, LD10-TRV-PDS, LD10-220 TRV-MLH1, LD10-TRV-MSH2 and LD10-TRV-MSH6, and of SN20 including 221 SN20-TRV2, SN20-TRV-PDS, SN20-TRV-MLH1, SN20-TRV-MSH2 and SN20-222 TRV-MSH6. For VIGS research, plasmids of TRV1, TRV2, and TRV2 223 construction derivatives (TRV-PDS, TRV-MLH1, TRV-MSH2 and TRV-MSH6) 224 were transformed into competent Agrobacterium tumefaciens strain GV3101 225 cells using a freeze-thaw method.<sup>34</sup> A single colony for each transformation 226 was selected and confirmed by colony PCR (primers listed in Table S2). The 227 verified bacterial cells were inoculated into 4 mL of liquid Luria-Bertani (LB) 228 medium (with 50 mg·L<sup>-1</sup> kanamycin and 40 mg·L<sup>-1</sup> gentamicin) on a rotary 229 shaker at 180 rpm at 28 °C for 16 h and grown to an OD 600 of 1.4-1.6. The 230 Agrobacterium strains were flash-frozen in liquid nitrogen with glycerol at a final 231 concentration of 30% (v/v) prior to storage at -80 °C. 232

The stored *Agrobacterium* strains (20  $\mu$ L) were inoculated into 3 mL of LB medium as above on a rotary shaker at 180 rpm at 28 °C for 24 h and grown to an OD<sub>600</sub> of 1.4-1.6. Then 1 mL of the culture was inoculated into 100 mL of LB medium and incubated as above for 12-16 h to an OD<sub>600</sub> of 1.0-1.2. The *Agrobacterium* cells were centrifuged at 3000 g at room temperature for 10 min, washed twice and then re-suspended using the infiltration solution (1/2 MS medium, 10 mM MgCl<sub>2</sub>, 10 mM MES, 200  $\mu$ M acetosyringone, pH 5.6 ) to a final

OD 600 of 0.7-0.8, and placed at 26 °C in darkness for 4 h. The infiltration 240 solution of the Agrobacterium strain containing TRV1 was mixed with TRV2 or 241 an infiltration solution of the Agrobacterium carrying the constructs at a 1 to 1 242 ratio (v/v). Silwet L77 (GE, USA) was added into the infiltration solution to a final 243 concentration of 0.05 % (v/v) and mixed well immediately. About 30 seeds with 244 homogenous germination were placed in a 150 mL flask containing 100 mL of 245 the infiltration mixture solution. Agrobacterium was infiltrated into soybean 246 sprouts using a vacuum dryer (DZF-6050, Jinghong, Shanghai, PR China). 247 Vacuum was maintained at -25 kPa for 15 s, then decompressed to 248 atmospheric pressure rapidly. In each experiment, the operation was repeated 249 three times. The treated seeds were grown hydroponically on 250 mL MS media 250 in a 250 mL flask for 18-20 days at 26 ± 1 °C with a light regime of 16 h light / 251 8 h dark, and the MS media was changed every other day. The homogeneous 252 root seedlings were then transferred into the MS liquid medium with 0 or 0.5 253 mg L<sup>-1</sup> Cd for 4 days. The incubation conditions and the root measuring method 254 were performed as described in section 2.1. 255

256 Statistical analysis

SPSS (version 23.0) was used for statistical analyses of the experimental data. Results are expressed as the means  $\pm$  standard deviation (SD) of three independent experiments. The data were analyzed by two-way analysis of variance (ANOVA) at *P* < 0.05. (Tables 1-2, Tables S1, S3-4). The differences in the same cultivar among the Cd treatment and the differences between the cultivars under the same Cd treatment were further evaluated by one-way ANOVA test at P < 0.05.

264 **Results** 

## 265 Cd stress suppressed the root growth of soybean seedlings

To investigate the effect of Cd stress on soybean seedling growth, a total of 266 twenty-two American and Chinese soybean cultivars were exposed to Cd (0.25-267 0.5 mg•L-1) stress for 4 days. There existed an obvious variation in the Cd-268 tolerance among the twenty-two soybean cultivars under Cd treatment (Table 269 S1). Two soybean cultivars contrasting in Cd sensitivity, Liaodou10 (LD10) and 270 Shennong 20 (SN20) were screen for downstream molecular studies. The 271 result showed that, Cd treatment (0.25-0.5 mg·L<sup>-1</sup>) had no statistically 272 273 significant (P < 0.05) effect on seed germination efficiency, fresh weight, and dry weight compared to the control in either LD10 or SN20 seedlings (Table 1). 274 However, 2.5 mg L<sup>-1</sup> Cd treatment significantly reduced the germination 275 percentage, fresh weight and dry weight of both LD10 and SN20 compared to 276 the control. Exposure to 0.25 mg·L<sup>-1</sup> Cd stress for 4 days significantly reduced 277 growth of LD10 roots, resulting a reduction in root length to 29.84% of the 278 control, and a dose-dependent decrease in root length was observed with 279 increasing Cd concentrations. In contrast, there were statistically significant 280 differences in root length between the control and Cd-treated SN20 seedlings 281 only at the Cd concentrations above 0.5 mg·L<sup>-1</sup>, with a reduction in root length 282 to 24.96% of the control at 0.5 mg  $L^{-1}$  Cd and 46.16% at 2.5 mg  $L^{-1}$  Cd, 283

### respectively (Table 1 and Figure S1).

### **Table 1.** Effect of Cd stress (0-2.5 mg·L<sup>-1</sup>) on growth of LD10 and SN20 seedlings for 4

| 286 | days. |
|-----|-------|
|     |       |

| Cultivar             | Cd treatment<br>(mg·L <sup>-1</sup> ) | Germination<br>(%) | Fresh weight<br>(g) | Dry weight<br>(g) | Root length<br>(cm) | Length<br>reduction (%) |
|----------------------|---------------------------------------|--------------------|---------------------|-------------------|---------------------|-------------------------|
|                      | 0                                     | 72.45 ± 2.82a      | 3.89 ± 0.26a        | 0.77 ± 0.04a      | 5.63 ± 0.11a        | 0                       |
|                      | 0.25                                  | 70.48 ± 0.95a      | 3.88 ± 0.51a        | 0.77 ± 0.01a      | 3.95 ± 0.15b        | 29.84 ± 0.16c           |
| LD10                 | 0.5                                   | 70.69 ± 2.25a      | 3.74 ± 0.26b        | 0.74 ± 0.04a      | 2.58 ± 0.04c        | 54.17 ± 0.27b           |
|                      | 2.5                                   | 61.11 ± 1.11b      | 2.95 ± 0.18c        | 0.58 ± 0.08b      | 1.38 ± 0.06d        | 75.49 ± 0.09a           |
|                      | 0                                     | 82.94 ± 3.10a      | 3.64 ± 0.18a        | 0.79 ± 0.05a      | 7.17 ± 0.15a        | 0                       |
| CNICO                | 0.25                                  | 80.60 ± 6.24a      | 3.65 ± 0.17a        | 0.78 ± 0.03a      | 6.92 ± 0.17a        | 3.49 ± 0.08c            |
| SN20                 | 0.5                                   | 77.26 ± 3.80a      | 3.49 ± 0.09b        | 0.77 ± 0.01a      | 5.31 ± 0.11b        | 25.94 ± 0.15b           |
|                      | 2.5                                   | 65.19 ± 1.15b      | 3.02 ± 0.08c        | 0.67 ± 0.04b      | 3.86 ± 0.31c        | 46.16 ± 0.21a           |
| Source of variation  |                                       |                    |                     |                   |                     |                         |
| Cultivar (C) (df=1)  |                                       | 36.89 **           | 0.27NS              | 171.57**          | 1421.44**           | 75956.56**              |
| Treatment (T) (df=3) |                                       | 25.33 **           | 208.93**            | 6.39**            | 664.93**            | 122428.92**             |
| C×T (df=3)           |                                       | 1.41NS             | 1.55NS              | 4.25*             | 23.6**              | 8504.53**               |

\*, significant at the *P* < 0.05 level; \*\*, significant at the *P* < 0.01 level. NS, Not significant.

288 For the same cultivar, different letters indicate statistically significantly differences (*P* < 0.05)

among different Cd treatment. Standard deviations were calculated with five independent

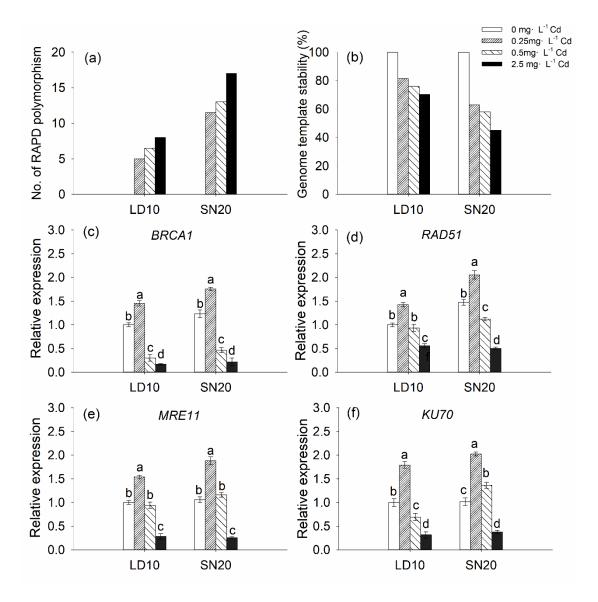
290 experiments each comprising 35 soybean seedlings.

## 291 Cd stress induced DNA damage in soybean seedling roots

DNA damage levels in LD10 and SN20 seedling roots grown under Cd 292 stress for 4 days was assessed using a RAPD assay on DNA extracted from 293 the control and Cd-treated (0.25-2.5 mg·L<sup>-1</sup>) seedling root tips. Cd stress 294 significantly increased the frequency of RAPD polymorphism even at low 295 296 concentrations and substantially decreased the stability of the genome template in both LD10 and SN20 roots compared with the control (Figure 1a-b, Figure 297 S2). Interestingly, higher RAPD polymorphism and more reduction in the 298 299 stability of genome template occurred in SN20 root tips than those in LD10

300 under Cd stress of 0.25-2.5 mg·L<sup>-1</sup>.

The transcriptional regulation of DNA damage repair genes BRCA1, RAD51, 301 MRE11 and KU70 was studied by qRT-PCR analysis in LD10 and SN20 302 seedling roots under Cd stress. gRT-PCR analyses results indicate that the 303 expression levels of these DNA damage repair genes, involved in HR (RAD51 304 and BRCA1) and NHEJ (MRE11 and KU70) were significantly up-regulated by 305 0.25 mg·L<sup>-1</sup> Cd stress in both LD10 and SN20 seedling roots compared with 306 the control (Figure 1c-f). Moreover, SN20 showed higher expression level of 307 these DNA damage repair genes than LD10 did under 0.25 mg L<sup>-1</sup> Cd stress. 308 However, 0.5 mg·L<sup>-1</sup> Cd stress significantly down-regulated the expression 309 levels of BRCA1 and KU70 genes in LD10 seedling roots, and of BRCA1 and 310 RAD51 genes in SN20 seedling roots. A higher concentration (2.5 mg L<sup>-1</sup>) of 311 Cd treatment down-regulated the expression levels of all of these genes in both 312 LD10 and SN20 seedling roots (Figure 1c-f). Taken together, the results indicate 313 that Cd stress can induce higher expression of DNA damage regulatory genes 314 in SN20 than in LD10 seedling roots. 315



316

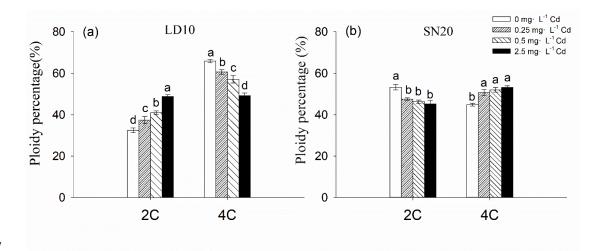
Figure 1. Cd stress induced DNA damage in LD10 and SN20 seedling root tips when grown under 0-2.5 mg·L<sup>-1</sup> Cd stress for 4 days. (a) RAPD polymorphism variation; (b) The GTS; (c-f) The relative expression level of DNA damage repair genes. Gene expression levels of the LD10 under control conditions were set to 1 as the normalization in qRT-PCR analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significantly differences (P < 0.05).

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## 324 Cd stress induced the cell cycle progression arrest in soybean root tips.

To evaluate cell cycle progression in root tips of LD10 and SN20 seedlings

grown under Cd stress (0-2.5 mg L<sup>-1</sup>) for 4 days, the ploidy was determined 326 using FCM analysis. Cd treatment significantly increased the proportion of 2C 327 nuclear content (G0/G1 phase) cells (by 15.4-50.5%) in root tips of LD10 328 seedlings compared to the control (32.46%), while the proportion of 4C nuclear 329 content cells decreased significantly by 7.9-24.9% (Figure 2a and Figure S3). 330 In contrast, the proportion of 2C nuclear content cells in SN20 seedling root tips 331 under Cd stress decreased by 10.9-15.3% when compared with the control 332 (53.33 %), but the proportion of 4C nuclear content cells increased by 12.1-333 334 18.5% (Figure 2b). The FCM results indicate that Cd stress could induce a G1/S phase arrest in root tips of Cd-sensitive soybean genotype LD10, and G2/M 335 phase arrest in root tips of Cd-tolerant soybean genotype SN20, respectively. 336



337

Figure 2. FCM analysis of the nuclear DNA contents of soybean genotypes LD10 (a) and SN20 (b) seedling roots under Cd stress for 4 days. The percentage of 2C and 4C nuclear content cells in the total cell population was calculated. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05).

To assess the cell cycle progression in root tips of soybean seedlings after 343 Cd stress for 4 days, the expression levels of PCNA1, E2Fa and HISTONE H4 344 (G1/S phase transition regulation/marker genes), ATM and ATR (DNA damage 345 response genes), CYCB1:1, CDKA:1 and WEE1 (G2/M phase transition 346 regulation/marker genes) were measured in the LD10 and SN20 seedling root 347 tips by gRT-PCR. Expression levels of PCNA1, E2Fa, HISTONE H4, CYCB1;1 348 and CDKA;1 were significantly down-regulated with a dose-dependent 349 response related to the concentration of Cd treatment in both LD10 and SN20 350 seedling root tips (Figure 3). In contrast, in root tips of both LD10 and SN20 351 seedlings, the expression level of WEE1, ATM and ATR genes was up-352 regulated by 1.2 to 1.7- fold at 0.25 mg L<sup>-1</sup> Cd treatment, but a dose-dependent 353 354 decrease was observed in the expression of WEE1 with Cd concentrations  $\geq$ 0.5 mg L<sup>-1</sup> and a significant suppression in expression of ATM and ATR genes 355 only at 2.5 mg L<sup>-1</sup> Cd. Interestingly, SN20 root tips showed higher expression 356 level of ATR and lower level of ATM than those of LD10 under 0.25 mg·L<sup>-1</sup> Cd 357 stress. Taken together, these data indicate that Cd stress had striking effects 358 on the expression of cell cycle marker genes in LD10 and SN20 seedling root 359 tips, and provides evidence towards the hypothesis that Cd stress induces G1/S 360 phase arrest in LD10 and G2/M phase arrest in SN20 seedling root tips. 361

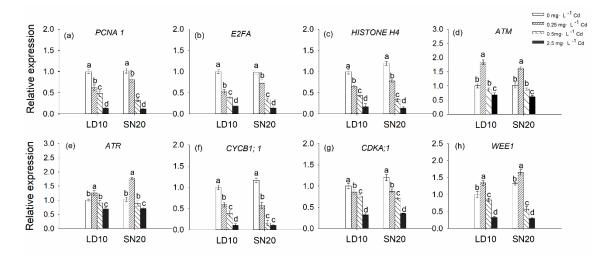




Figure 3. Relative gene expression levels in root tips of LD10 and SN20 seedling exposed to 0-2.5 mg·L<sup>-1</sup> Cd for 4 days. In a-h, G1/S phase transition regulation / marker genes *PCNA1, E2FA, HISTONE H4*; DNA damage response genes *ATM, ATR*; G2/M phase transition regulation / marker genes *CYCB1;1, CDKA;1, WEE1*. Gene expression levels of the LD10 seedling root tips under normal condition were set to 1 as the normalization for qRT-PCR analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05).

## 370 Cd stress regulated MMR transcripts in soybean seedling roots

To investigate the role of the MMR system in the Cd-induced DNA damage 371 response pathway in soybean, the transcriptional regulation of MMR genes was 372 determined by gRT-PCR analysis. As shown in Figure 4, exposure to Cd stress 373 (0.25-0.5 mg·L<sup>-1</sup>) for 4 days significantly decreased the expression level of 374 MLH1 and MSH6 in both SN20 and LD10, but MSH2 was only down regulated 375 in SN20 root tips compared with the control at these Cd concentrations. 376 However, expression of all three genes was significantly down-regulated by 2.5 377 mg L<sup>-1</sup> Cd treatment in both LD10 and SN20. Surprisingly, the expression levels 378

of *MSH2* and *MSH6* genes were significantly (P < 0.05) higher in SN20 than those in LD10 root tips under the control conditions. Inversely, LD10 had a higher *MSH6* expression level than SN20 did when exposed to Cd stress (0.25-2.5 mg·L<sup>-1</sup>) for 4 days. The above results reveal a significant difference in basal expression of *MSH2* and *MSH6* between LD10 and SN20 cultivars under normal conditions, while showing Cd hypersensitivity of *MLH1* in LD10 and *MSH2* and *MSH6* in SN20.

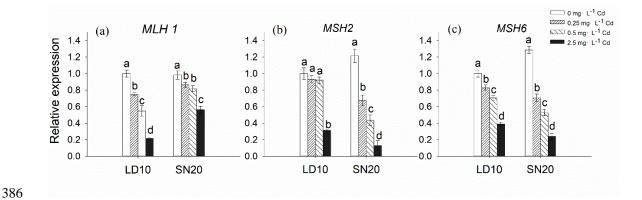
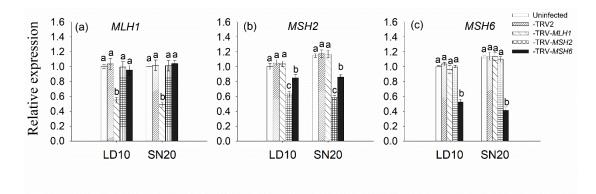


Figure 4. Relative gene expression levels of *MLH1* (a), *MSH2* (b), and *MSH6* (c) genes in root tips of LD10 and SN20 seedling exposed to 0-2.5 mg·L<sup>-1</sup> Cd for 4 days. Gene expression levels of the LD10 seedling roots under normal condition were set to 1 as the normalization in the qRT-PCR analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P <0.05).

## 393 Soybean MMR-silenced plants developed by VIGS

*MLH1*, *MSH2* and *MSH6* genes silencing seedlings of LD10 and SN20 were developed using a TRV-based VIGS system to further understand the role of MMR genes in soybean Cd tolerance. The soybean *PDS* gene, encoding a key enzyme in the carotenoid synthesis pathway, was used as a reporter gene for
testing the TRV-based gene silencing efficiency in soybean plantlets. As shown
in Figure 5a-d, the newly formed leaves of the TRV-*PDS* plantlets of LD10 and
SN20 showed very obvious photo-bleaching compared with the uninfected
plants at 20 days after *Agrobacterium* infection (Figure S5). Likewise, 85.3388.05% TRV-*PDS* infected plants showed a photo-bleaching phenotype (Figure
S5).

To confirm suppression of the MLH1, MSH2 and MSH6 genes using the 404 405 TRV-based VIGS system, transcript levels were measured by gRT-PCR using gene-specific primers (Table S2). As shown in Figure 5a-c, the expression 406 levels of MLH1, MSH2 and MSH6 genes in their corresponding TRV-based 407 408 MMR gene silencing plantlets were significantly reduced (P < 0.05) when compared with the TRV2 infected or the uninfected plants. In contrast, the 409 transcript level of housekeeping genes (Tubulin A and Actin gene) or cell cycle-410 regulation genes including PCNA1, E2Fa, HISTONE H4, CYCB1;1, CDKA;1 411 and WEE1 was not significantly different between the TRV-based gene 412 silencing plants and TRV2 or the uninfected plant root tips under normal culture 413 conditions (Figure S6). This demonstrates that there was no general effect on 414 mRNA stability in the MMR-silenced soybean root tips, suggesting that the 415 effects were transcript specific. In addition, the LD10/SN20-TRV-based gene 416 silencing plants showed no visible root phenotype differences under normal 417 growth conditions compared to the corresponding TRV2 and the LD10/SN20 418



#### uninfected plants (Figure S7, Table S4). 419

420

Figure 5. VIGS induced soybean MMR gene silencing. Relative gene expression levels 421 422 of MLH1 (a), MSH2 (b), and MSH6 (c) genes in root tips of TRV-based MMR gene 423 silencing soybean plantlet under normal culture conditions. Gene expression levels of the uninfected LD10 seedling roots were set to 1 as the normalization in the qRT-PCR 424 425 analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05). 426

#### Soybean MMR system was involved in the Cd-induced root growth 427 inhibition 428

To investigate the effect of the MMR system on the tolerance of soybean 429 roots to Cd toxicity, uninfected LD10 and SN20 plantlets and their VIGS-induced 430 gene silencing lines (including TRV2, TRV-MLH1, TRV-MSH2 and TRV-MSH6 431 plantlets) were exposed to 0.5 mg L<sup>-1</sup> Cd stress for 4 days. Cd stress 432 significantly inhibited total root length and total root area, but not root diameter 433 in both uninfected LD10 and SN20 seedlings compared with the corresponding 434 control (Table 2, Figure S7). Unexpectedly, total root length and total root area 435 436 were significantly higher in LD10-TRV-MLH1 than those in LD10, LD10-TRV, LD10-TRV-MSH2 and LD10-TRV-MSH6 lines with similar phenotypes under 437

| 438 | 0.5 mg·L <sup>-1</sup> Cd stress for 4 days. However, total root length and total root area        |
|-----|--|
| 439 | in SN20-TRV-MSH2 and SN20-TRV-MSH6 seedlings were significantly                                    |
| 440 | reduced compared with the uninfected SN20, SN20-TRV2 and SN20-TRV-                                 |
| 441 | <i>MLH1</i> seedlings under 0.5 mg·L <sup>-1</sup> Cd stress. Taken together, the results indicate |
| 442 | that VIGS-induced MLH1 gene silencing increased Cd toxicity resistance in the                      |
| 443 | LD10 line, while MSH2 and MSH6 gene silencing decreased Cd toxicity                                |
| 444 | resistance in the SN20 line.   |

- 445 **Table 2.** Effect of Cd stress on root growth of TRV-based MMR gene silencing soybean
- 446 plantlets for 4 days.

| Soybean lines        | Cd treatment<br>(mg⋅L <sup>-1</sup> ) | Total root length<br>(cm) | Total root area<br>(cm <sup>2</sup> ) | Root diameter<br>(mm) |
|----------------------|---------------------------------------|---------------------------|---------------------------------------|-----------------------|
| LD10                 | 0                                     | 132.64 ± 9.32 b           | 24.39 ± 2.89 b                        | 0.61 ± 0.04 a         |
| LD10                 | 0.5                                   | 68.84 ± 2.85 f            | 10.19 ± 1.43 f                        | 0.52 ± 0.05 a         |
| LD10-TRV2            | 0.5                                   | 68.61 ± 3.05 f            | 10.22 ± 1.05 f                        | 0.56 ± 0.04 a         |
| LD10-TRV-MLH1        | 0.5                                   | 83.11 ± 3.75 e            | 13.52 ± 0.69 e                        | 0.55 ± 0.03 a         |
| LD10-TRV-MSH2        | 0.5                                   | 66.91 ± 1.84 f            | 11.02 ± 0.82 f                        | 0.56 ± 0.03 a         |
| LD10-TRV-MSH6        | 0.5                                   | 64.35 ± 3.26 f            | 10.22 ± 1.05 f                        | 0.56 ± 0.09 a         |
| SN20                 | 0                                     | 147.9 ± 2.17 a            | 31.09 ± 0.98 a                        | 0.53 ± 0.04 a         |
| SN20                 | 0.5                                   | 111.09 ± 2.83 c           | 20.62 ± 1.23 c                        | 0.58 ± 0.05 a         |
| SN20-TRV2            | 0.5                                   | 112.37 ± 5.33 c           | 20.42 ± 1.30 c                        | 0.57 ± 0.03 a         |
| SN20-TRV-MLH1        | 0.5                                   | 106.58 ± 5.39 c           | 19.38 ± 0.75 c                        | 0.55 ± 0.04 a         |
| SN20-TRV-MSH2        | 0.5                                   | 94.66 ± 4.91 d            | 16.11 ± 0.97 d                        | 0.53 ± 0.08 a         |
| SN20-TRV-MSH6        | 0.5                                   | 90.13 ± 2.66 d            | 16.18 ± 0.99 d                        | 0.52 ± 0.06 a         |
| Source of variation  |                                       |                           |                                       |                       |
| Cultivar (C) (df=9)  |                                       | 20.14**                   | 23.56**                               | 0.98NS                |
| Treatment (T) (df=1) |                                       | 632.34**                  | 535.58**                              | 0.02NS                |
| C×T (df=9)           |                                       | 4.4**                     | 2.05NS                                | 1.18NS                |

447 Standard deviations were calculated with three independent experiments. For each

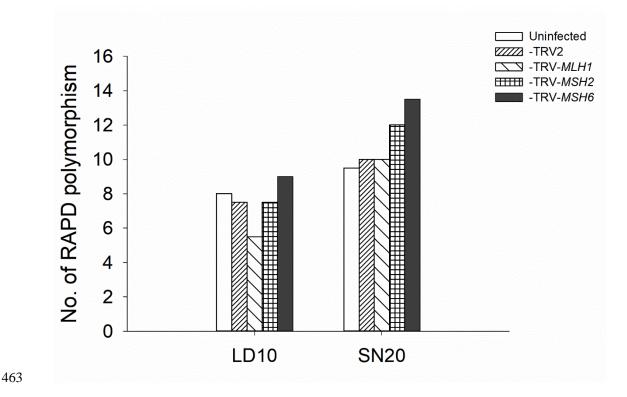
448 experiment, at least 10 soybean seedling plants were used for each treatment. Different

449 letters indicate statistically significant differences (*P* < 0.05).

## 450 **Contribution of the soybean MMR system in the Cd-induced DNA damage**

451 To assess the role of soybean MMR proteins in the Cd-induced DNA

damage signaling pathway, DNA damage levels of LD10 and SN20 roots 452 exposed to 0.5 mg·L<sup>-1</sup> Cd for 4 days were analyzed by a RAPD assay and 453 compared to the VIGS silencing lines. As shown in Figure 6 and Figure S8, Cd 454 treatment significantly increased the frequencies of RAPD polymorphism in 455 LD10 and SN20 seedling roots compared with the untreated control plantlets. 456 LD10-TRV-*MLH1* plantlet roots showed significantly less RAPD polymorphism 457 compared to all the other LD10 lines. In contrast, SN20-TRV-MSH2 and SN20-458 TRV-*MSH6* showed more polymorphic RAPD bands compared to the other 459 460 SN20 lines. Taken together, these results suggest that in LD10, MLH1 may not determine DNA stability, while in SN20, MSH2 and MSH6 may promote DNA 461 stability in soybean roots under Cd stress. 462



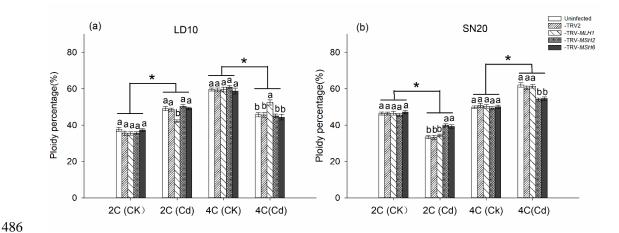


465 plantlets exposed to 0.5mg·L<sup>-1</sup> Cd for 4 days. For all treatments, reproducible bands in at

466 least two replicates were evaluated and calculated for polymorphism analysis.

# 467 Contribution of the soybean MMR system in the Cd-induced cell cycle 468 arrest

To investigate the contribution of the MMR system in Cd-induced cell cycle 469 progression arrest, 1 cm long root tips of LD10 and SN20 lines exposed to 0.5 470 mg L<sup>1</sup>Cd stress for 4 days were harvested for cell cycle progression analysis 471 using FCM. As shown in Figure 7 and Figure S9, Cd-induced G1/S arrest was 472 significantly attenuated in the LD10-TRV-MLH1 compared with the uninfected 473 LD10 or TRV2 seedling roots under 0.5 mg L<sup>-1</sup> Cd stress. The 2C nuclear 474 content decreased by 14.1%, while the 4C nuclear content increased by 14.7% 475 in LD10-TRV-MLH1 seedling roots relative to the uninfected LD10 under Cd 476 stress. However, in the SN20-TRV-MSH2 and SN20-TRV-MSH6 roots, 0.5 477 mg L<sup>-1</sup> Cd stress significantly increased the proportion of cells with 2C nuclear 478 content, which was 19.5% and 17.6% compared with the uninfected SN20 479 (Figure 7); whereas there was a reduction of 4C nuclear content by 12.9% and 480 12.1%, respectively. The results indicate that Cd-induced G2/M arrest was 481 attenuated in the SN20-TRV-MSH2 and TRV-MSH6 seedling roots. Taken 482 together, the results indicate that MLH1 is involved in the Cd-induced G1/S 483 phase arrest, while MSH2 and MSH6 are involved in the Cd-induced G2/M 484 phase arrest in root tips of soybean seedlings. 485



**Figure 7.** FCM analysis of the nuclear DNA contents of soybean genotypes LD10 (a) and SN20 (b) seedling roots under 0-0.5 mg·L<sup>-1</sup> Cd stress for 4 days. The percentage of 2C and 4C nuclear content cells in total cells was calculated, respectively. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05). \* indicate statistically significant differences (P < 0.05)

qRT-PCR results showed that exposure to 0.5 mg·L<sup>-1</sup> Cd stress for 4 days 492 493 significantly influenced the expression levels of DNA damage response and repair genes in LD10, SN20 and their VIGS-induced gene silencing seedling 494 roots compared with the control (Figure 8). Notably, LD10-TRV-MLH1 seedling 495 roots showed higher gene expression levels of *MLH1*, *MSH6*, *BRCA*, *RAD51* 496 and KU70, but lower gene expression levels of MSH2 and ATM, compared 497 with the uninfected LD10 and LD10-TRV seedling roots under 0.5 mg·L<sup>-1</sup> Cd 498 stress for 4 days. Similar expression levels of the same DNA damage response 499 and repair genes occurred in LD10-TRV-MSH2 and LD10-TRV-MSH6 seedling 500 roots compared with the uninfected LD10 and LD10-TRV2 seedling roots 501 under 0.5 mg·L<sup>-1</sup> Cd treatment for 4 days, with the exception that *MSH*2 and 502 *MSH6* gene expression, which was reduced. 503

| 504 | However, in SN20-TRV-MSH2 seedling roots, expression levels of some                              |
|-----|--|
| 505 | genes (i.e. MLH1, MSH2, MSH6, ATR, BRCA1 and RAD51) were significantly                           |
| 506 | reduced, while others such as ATM and KU70 were up-regulated (i.e. an                            |
| 507 | increase of 1.13- to 1.23- fold) compared with those in the SN20 or SN20-TRV                     |
| 508 | root tips under Cd stress of 0.5 mg·L <sup>-1</sup> ( $P < 0.05$ ). A similar trend appeared in  |
| 509 | SN20-TRV-MSH6 seedling roots. Furthermore, expression levels of PCNA1,                           |
| 510 | E2FA, HISTONE H4 were significantly higher in LD10-TRV-MLH1 seedling                             |
| 511 | roots than those in uninfected LD10, LD10-TRV2 and LD10-TRV-MSH2/6                               |
| 512 | seedling roots exposed to 0.5 mg·L <sup>-1</sup> Cd stress for 4 days (Figure S10). In           |
| 513 | contrast, there were no significant differences in the expression levels of                      |
| 514 | PCNA1, E2FA, HISTONE H4, CYCB1;1, CDKA;1, or WEE1 genes between                                  |
| 515 | the SN20-TRV-MSH2 and the SN20/SN20-TRV2 seedling roots exposed to Cd                            |
| 516 | stress of 0.5 mg·L <sup>-1</sup> . A similar trend occurred in SN20-TRV- <i>MSH6</i> , SN20-TRV- |
| 517 | MLH1, LD10-TRV-MSH2, and LD10-TRV-MSH6 seedling roots (Figure S10).                              |

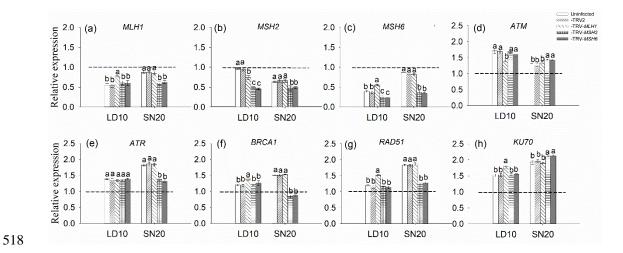


Figure 8. Relative gene expression levels of DNA damage repair genes in seedling roots
of LD10 and SN20 genotypes exposed to 0.5 mg·L<sup>-1</sup> Cd for 4 days. Dashed line indicate

521 gene expression levels of LD10 seedling roots grown under control conditions were set to 522 1 as the normalization in qRT-PCR analysis. Standard deviations were calculated with 523 three independent experiments. Different letters indicate statistically significant 524 differences (P < 0.05) in a to h.

525 **Discussion** 

Exposure to Cd stress inhibits plant growth and metabolism, and induces 526 different types of DNA damage including DNA single strand breaks (SSB) and 527 double strand breaks (DSB).<sup>35</sup> DNA damage signals lead to: (1) activation of 528 529 cell cycle checkpoints resulting in cell cycle arrest, and activation of DNA repair pathways, or (2) induction of apoptosis.<sup>36,37</sup> Previous studies identified the role 530 of the MMR system in Cd toxicology and that MSH2 and MSH6 primarily 531 contribute to Cd-induced G<sub>2</sub>/M arrest causing suppressed growth of 532 Arabidopsis roots.<sup>4,27</sup> In this study, exposure to (0.25-2.5 mg·L<sup>-1</sup>) Cd stress for 533 4 days inhibited the growth of soybean seedling roots. Two contrasting soybean 534 cultivars, LD10 (Cd-sensitive) and SN 20 (Cd-tolerant) were used to study the 535 mechanism of cultivar-dependent Cd stress responses in soybean. 536

537 There was a significant difference in DNA damage and cell cycle arrest

538 between LD10 and SN20

RAPD analysis indicated that exposure to Cd stress for 4 days, even at low
concentrations (0.25 mg·L<sup>-1</sup>), could induce DNA damage in both Cd-sensitive
soybean cultivar LD10 and in Cd-tolerant soybean cultivar SN20 (Figure 1a).
This result is consistent with previous researches in Arabidopsis, rice and

barley.<sup>4,6,38</sup> Interestingly, although LD10 showed a higher reduction in root 543 length than SN20 when exposed to Cd (0.25-2.5 mg L<sup>-1</sup>) stress for 4 days, LD10 544 showed higher genomic stability than SN20 (Figure 1b). Furthermore, the 545 expression levels of DNA DSB repair genes (i.e. BRCA1, RAD51, MRE11 and 546 KU70) in SN20 seedling roots were significantly higher than those in LD10 547 under corresponding Cd stress, suggesting that SN20 had suffered more 548 serious DSBs induced by Cd stress than LD10 did. Previous studies have 549 shown that RAD51 and BRCA1 are responsible for repair of DSBs via HR.<sup>39</sup> 550 HR needs the homologous sequence of the uninjured sister chromatid as a 551 template for DNA damage repair, which is a complex but precise process for 552 repairing DNA damage. In contrast, MRE11 and KU70 are involved in repairing 553 DSBs via NHEJ.<sup>40</sup> Instead of relying on homologous DNA sequences, the NHEJ 554 pathway directly connects the ends of DSBs using DNA ligase, which is a fast 555 DSBs repair process, but can result in deletions and insertions. Although high-556 fidelity genetic information is very important for organisms, perhaps it is more 557 beneficial for organisms to tolerate some DNA damage rather than to allow the 558 replication fork to collapse.<sup>29</sup> The DNA damage tolerance (DDT) phenomenon 559 is widespread in eukaryotic cells, allowing the organism to avoid compromised 560 genome integrity or cell death.<sup>29,41</sup> Here we show that although multiple DNA 561 repair systems were more highly activated in the Cd tolerant SN20 cultivar, DNA 562 damage was still greater than in the more sensitive LD10, thus the abiotic 563 stress-induced DNA damage was not fully avoided. 564

The above results might be related to the different points in the cell cycle 565 where the cells arrest: Cd-induced G1/S phase cell cycle progression arrest in 566 LD10 seedling roots and G2/M phase cell cycle arrest in SN20 seedling roots 567 (Figure 2). DNA damage can activate checkpoint pathways at different phases 568 of the cell cycle.<sup>42</sup> Cd-induced G1/S phase cell cycle arrest in LD10 (Cd-569 570 sensitive) seedling roots inhibited DNA replication, causing an increase of 2C nuclear content, however. This may contribute to the increased stability of the 571 genomic DNA, due to higher fidelity of DNA replication compared to SN20, 572 although Cd still seriously inhibited root growth (Table 1, Figures 1 and 2). G2/M 573 phase arrest in SN20 seedling roots inhibited mitosis, leading to the increase of 574 4C nuclear content and lower genomic stability. Possibly through translesion 575 DNA synthesis (TLS) mechanisms,<sup>43</sup> DNA replication in S phase is permitted 576 using damaged DNA as a template to keep soybean plantlets growing. This 577 then resulted in DNA damage spreading, as seen by greater RAPD 578 polymorphism in SN20 than in LD10 roots (Table 1, Figures 1 and 2). 579

580

## 581 Differentially expressed and responsive MMR genes determine Cd-582 induced root growth repression in soybean by regulating the cell cycle

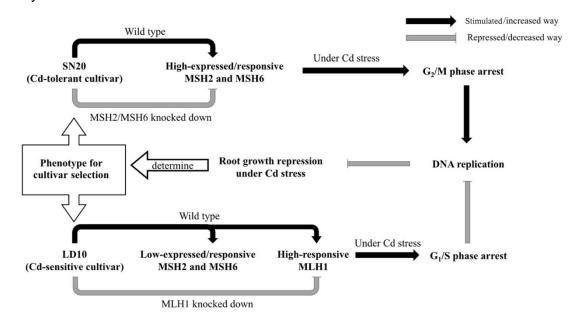
583 Results from the present study (Figure 4) indicate the significantly different 584 basal-expression of MMR genes between LD10 and SN20. This is integrated 585 with cell cycle arrest, accounting for the Cd-tolerant characteristics in soybean. 586 As is known, the MMR system not only corrects biosynthetic errors, but also

surveys DNA damage and participates in the regulation of cell cycle progression 587 in response to abiotic stress induced DNA damage.<sup>16,44,45</sup> This was shown in 588 Arabidopsis *msh2* and *msh6* mutants in our previous work.<sup>46</sup> In this study, the 589 higher expression of MSH2 and MSH6 in SN20 indicate their preferential 590 recognition of the DNA damage, resulting in G<sub>2</sub>/M phase arrest via MutS-to-591 ATR/ATRIP signaling (Figures 9 and 10). However, Cd-induced G<sub>2</sub>/M phase 592 arrest allows DNA replication, which causes cell volume enlargement and some 593 cell proliferation with post-replication repair, accounting for the Cd-tolerant root 594 growth in SN20. In contrast, the lower expression of MSH2 and MSH6 in LD10 595 bypasses the MMR system monitoring of DNA damage, leading to G<sub>1</sub>/S phase 596 arrest. This occurs prevailingly via the MRN complex-to-ATM signaling which is 597 a DSB recognition pathway with participation of MLH1.<sup>26,47</sup> G<sub>1</sub>/S phase arrest 598 blocks the cell cycle from entering into S phase to prevent DNA replication, 599 which explains the Cd-sensitive root growth in LD10. 600

To validate the above hypothesis, MMR genes were knocked down by 601 amiRNAs (artificial miRNAs) using TRV-induced VIGS technology. SN20, the 602 Cd-tolerant cultivar, showed higher expression and responsiveness of MSH2 603 and MSH6 to the Cd stress, resulting in less root growth repression because of 604 G<sub>2</sub>/M phase arrest. However, in SN20-TRV-MSH2 and SN20-TRV-MSH6 605 seedlings G<sub>2</sub>/M phase arrest was reduced and Cd-induced root growth 606 repression increased. This strongly indicates that it is MSH2 and MSH6 607 expression that decreases root growth repression by regulating G<sub>2</sub>/M phase 608

arrest in SN20. Although root growth was also repressed in SN20-TRV-*MLH1*,
the repression was not significant. However, knocking down the expression of *MLH1* in LD10 reduced G<sub>1</sub>/S phase arrest. This provides evidence that in LD10,
MLH1 that is engaged in the MRN complex-to-ATM pathway regulating G<sub>1</sub>/S
phase arrest, is responsible for the greater Cd-induced root growth repression
compared to SN20.

Taken together the results can be used to build a model for how MMR genes regulate Cd tolerance by regulating the phase of cell cycle arrest and root growth repression (Figure 9). Thus, differentially expression of *MSH2* and *MSH6* play a crucial role in determining the intervarietal Cd tolerance in soybean.



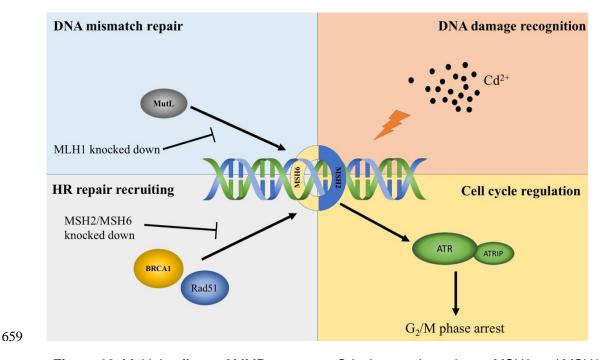
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Figure 9. Mechanism of Cd tolerance in soybean SN20 and LD10 cultivars. SN20 and LD10 were respectively Cd-tolerant and Cd-sensitive soybean cultivars selected by Cdinduced root growth repression. In wild type SN20 *MSH2* and *MSH6* are more highly expressed and are more responsive to Cd-stress than in LD10. This causes G<sub>2</sub>/M phase arrest in SN20 but  $G_1/S$  phase arrest in LD10 under Cd stress.  $G_2/M$  phase arrest in SN20 allows DNA replication leading to cell volume enlargement and some cell proliferation with post-replication repair, but  $G_1/S$  phase arrest in LD10 does not. This explains the different Cd-induced root growth repression in SN20 and LD10. This hypothesis was tested by knocking down *MSH2* or *MSH6* from SN20, and by knocking down *MLH1* from LD10 increasing  $G_1/S$  phase arrest through blocking the MRN complex-to-ATM signaling.

# The MMR system plays multiple roles in Cd-tolerance mechanisms of soybean

Differential expression of MSH2 and MSH6 are shown here to influence 633 root growth under Cd stress through regulating the cell cycle. Comparing DNA 634 damage and expression of DNA repair related genes between the LD10 and 635 636 SN20 wild type and MMR-knocked down plants, another vital role of the MMR system in Cd tolerance is revealed in recruiting DSB repair. BASC, a complex 637 of BRCA1-associated proteins, is involved in several functions such as DNA 638 damage recognition and binding, DNA repair, and downstream activation, in 639 which BRCA1, as the central component of BASC and of HR repair, was found 640 to interact with MSH2 and MSH6.48 The repressed expression of BRCA1 and 641 RAD51 genes in SN20-TRV-MSH2 and SN20-TRV-MSH6 seedlings (Figure 8), 642 suggests a recruitment effect of the MMR system, which was also found in our 643 previous study.<sup>27</sup> Indeed, DNA damage was not reduced even though there was 644 decreased G<sub>2</sub>/M phase arrest in the TRV lines. In fact, it increased in SN20-645 TRV-MSH2/6 seedlings, which indicates weak DNA repair. Also, DNA damage 646

was not increased as a result of the increased entry into DNA replication caused 647 by reduced G<sub>1</sub>/S phase arrest in LD10-TRV-*MLH1*. Indeed DNA damage was 648 reduced in the LD10-TRV-MLH1 seedling roots, suggesting enhanced DNA 649 repair. MMR and HR repair systems are attributed to post-replication repair and 650 act in the G<sub>2</sub> phase.<sup>46</sup> This explains the increased or decreased DNA damage 651 in SN20-TRV-MSH2/6 and LD10-TRV-MLH1 seedlings, respectively. In 652 conclusion, the MMR system not only participates in DNA mismatch repair, DNA 653 error surveillance, and cell cycle regulation, but also recruits HR repair 654 associated proteins in G<sub>2</sub> phase for repairing both SSBs and DSBs,<sup>49</sup> faithfully 655 maintaining genomic integrity and stability (Figure 10). This supplements Cd 656 tolerance and toxicological mechanisms, and moreover provides biomarkers 657 658 and a molecular basis for selection of Cd-tolerant cultivars.



**Figure 10.** Multiple effects of MMR system on Cd tolerance in soybean. MSH2 and MSH6

forming MutS $\alpha$  regulate the cell cycle by activating the G<sub>2</sub>/M checkpoint, leading to cell

cycle arrest, when they recognize Cd-induced DNA damage. Furthermore, MutSα can recruit MutL and BRCA1/Rad51 to trigger MMR and HR mediated repair. When *MSH2* or *MSH6* was knocked down, HR repair would be repressed causing increased SSBs and DSBs. Knocking down *MLH1* would suppress MMR, but improve HR repair because of reduced  $G_1/S$  arrest leading to enhanced post-replication repair in increased  $G_2$  phase.

This is the first report revealing the mechanisms acting in the differential 667 Cd-tolerance of soybean SN20 and LD10 cultivars including Cd-induced DNA 668 damage, DNA repair and cell cycle arrest. Differentially expressed MSH2 and 669 670 MSH6 play a crucial role in Cd-induced root growth repression. A model is proposed in which higher expression of MSH2 and MSH6 in SN20 activate 671 MutS-to-ATR/ATRIP signaling, causing G<sub>2</sub>/M arrest when Cd-induced DNA 672 673 damage is detected. This still allows DNA replication, leading to cell volume enlargement and proliferation after post-replication repair mechanisms such as 674 MMR and HR repair are activated. In contrast, LD10 with a lower expression of 675 MSH2 and MSH6 bypass the MMR system activating MLH1 that participates in 676 MRN complex-ATM signaling. This causes G<sub>1</sub>/S arrest and inhibits DNA 677 replication. In addition, the HR repair system is recruited by MSH2 and MSH6 678 to enhance post-replication repair, thus maintaining genomic integrity and 679 stability under Cd stress. This model explains inter-variety Cd tolerance in 680 soybean and provides both biomarkers and a molecular basis for selection of 681 682 Cd-tolerant cultivars.

## 683 Abbreviations

| BER | Base excision repair      | MMR  | DNA mismatch repair                |
|-----|---------------------------|------|------------------------------------|
| CDK | Cyclin-dependent kinases  | NER  | Nucleotide excision repair         |
| DDR | DNA damage response       | NHEJ | Non-homologous end joining         |
| DDT | DNA damage tolerance      | PAGE | Polyacrylamide gel electrophoresis |
| DSB | DNA double strand breaks  | PDS  | Phytoene desaturase                |
| FCM | Flow cytometry method     | SSB  | Single strand breaks               |
| GTS | Genome template stability | TLS  | Translesion DNA synthesis          |
| HR  | Homologous recombination  | TRV  | Tobacco rattle virus               |
| LB  | Luria–Bertani medium      | VIGS | Virus-induced gene silencing       |

## 684 Author contributions

- W.L., F.X. and H. W. designed the experiments. Q.Z., Y.D., Z.W., S.J. and X.Y.
  conducted the experiments. H.W. and Q.Z. analyzed the data. Q.Z., H.W. and
  W.L. wrote the manuscript. H.J.R. revised the manuscript. All authors read and
  approved the manuscript.
- 689 **Conflict of interest**
- 690 The authors declare no competing financial interest.

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## 695 Supporting Information

- <sup>696</sup> **Figure S1.** Growth performance of soybean seedlings exposed to 0-2.5 mg·L<sup>-</sup>
- <sup>697</sup> <sup>1</sup> Cd stress for 4 days.
- <sup>698</sup> **Figure S2.** RAPD fingerprints of soybean seedlings exposed to 0-2.5 mg·L<sup>-1</sup>Cd

- 699 stress for 4 days.
- Figure S3. FCM analysis of the nuclear DNA ploidy in LD10 (a) and SN20 (b)
- <sup>701</sup> seedlings exposed to 0-2.5 mg·L<sup>-1</sup> Cd stress for 4 days..
- 702 **Figure S4.** Vector maps.
- 703 **Figure S5.** VIGS induced soybean *PDS* gene silencing seedlings
- **Figure S6.** Relative gene expression levels of cell phase transition regulation
- genes in seedling roots of soybean VIGS plants under normal cultivation

706 conditions.

- 707 **Figure S7.** Growth performance of soybean VIGS plant seedlings exposed to
- 708 0.5 mg·L<sup>-1</sup> Cd stress for 4 days.
- 709 **Figure S8.** RAPD fingerprints of wild type and soybean VIGS seedlings.
- 710 **Figure S9.** FCM analysis of the nuclear DNA ploidy in soybean VIGS seedlings
- exposed to 0.5 mg·L<sup>-1</sup> Cd stress for 4 days
- 712 **Figure S10.** Relative gene expression levels of cell phase transition regulation
- genes in seedling roots of soybean VIGS plants exposed to 0.5 mg·L<sup>-1</sup> Cd for 4
- 714 days.
- **Table S1.** Effect of Cd stress (0-2.5 mg·L<sup>-1</sup>) on growth of soybean seedlings for
- 716 **4 days.**
- 717 **Table S2** Primer list
- Table S3. Variance analysis of gene expression in LD10 and SN20 seedlings
- 719 exposed to Cd stress for 4 days
- 720 **Table S4.** Variance analysis of gene expression in wild type and soybean

721 VIGS seedlings exposed to Cd stress for 4 days.

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- 849

850 **Figure captions** 

Figure 1. Cd stress induced DNA damage in LD10 and SN20 seedling root tips when grown under 0-2.5 mg·L<sup>-1</sup> Cd stress for 4 days. (a) RAPD polymorphism variation; (b) The GTS; (c-f) The relative expression level of DNA damage repair genes. Gene expression levels of the LD10 under control conditions were set to 1 as the normalization in qRT-PCR analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significantly differences (P < 0.05).

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Figure 2. FCM analysis of the nuclear DNA contents of soybean genotypes LD10 (a) and SN20 (b) seedling roots under Cd stress for 4 days. The percentage of 2C and 4C nuclear content cells in the total cell population was calculated. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05).

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Figure 3. Relative gene expression levels in root tips of LD10 and SN20
exposed to 0-2.5 mg·L<sup>-1</sup> Cd for 4 days. In a-h, G1/S phase transition regulation
/ marker genes *PCNA1*, *E2FA*, *HISTONE H4*; DNA damage response genes *ATM*, *ATR*; G2/M phase transition regulation / marker genes *CYCB1;1*, *CDKA;1*, *WEE1*. Gene expression levels of the LD10 seedling root tips under normal
condition were set to 1 as the normalization for qRT-PCR analysis. Standard
deviations were calculated with three independent experiments. Different letters

indicate statistically significant differences (P < 0.05).

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875 Figure 4. Relative gene expression levels of *MLH1* (a), *MSH2* (b), and *MSH6* (c) genes in root tips of LD10 and SN20 seedling exposed to 0-2.5 mg L<sup>-1</sup> Cd 876 for 4 days. Gene expression levels of the LD10 seedling roots under normal 877 condition were set to 1 as the normalization in the qRT-PCR analysis. Standard 878 deviations were calculated with three independent experiments. Different letters 879 indicate statistically significant differences (P < 0.05). 880 881 Figure 5. VIGS induced soybean MMR gene silencing. Relative gene 882 expression levels of MLH1 (a), MSH2 (b), and MSH6 (c) genes in root tips of 883 TRV-based MMR gene silencing soybean plantlet under normal culture 884 conditions. Gene expression levels of the uninfected LD10 seedling roots were 885 886 set to 1 as the normalization in the qRT-PCR analysis. Standard deviations 887 were calculated with three independent experiments. Different letters indicate

statistically significant differences (P < 0.05).

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Figure 6. RAPD polymorphism variations in roots of TRV-based gene silencing
soybean plantlets exposed to 0.5mg·L<sup>-1</sup> Cd for 4 days. For all treatments,
reproducible bands in at least two replicates were evaluated and calculated for
polymorphism analysis.

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**Figure 7.** FCM analysis of the nuclear DNA contents of soybean genotypes

LD10 (a) and SN20 (b) seedling roots under 0-0.5 mg·L<sup>-1</sup> Cd stress for 4 days. The percentage of 2C and 4C nuclear content cells in total cells was calculated, respectively. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P < 0.05). \* indicate statistically significant differences (P < 0.05)

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**Figure 8.** Relative gene expression levels of DNA damage repair genes in seedling roots of LD10 and SN20 genotypes exposed to 0.5 mg·L<sup>-1</sup> Cd for 4 days. Dashed line indicate gene expression levels of LD10 seedling roots grown under control conditions were set to 1 as the normalization in qRT-PCR analysis. Standard deviations were calculated with three independent experiments. Different letters indicate statistically significant differences (P <0.05) in a to h.

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Figure 9. Mechanism of Cd tolerance in soybean SN20 and LD10 cultivars. 910 911 SN20 and LD10 were respectively Cd-tolerant and Cd-sensitive soybean cultivars selected by Cd-induced root growth repression. In wild type SN20 912 MSH2 and MSH6 are more highly expressed and are more responsive to Cd-913 914 stress than in LD10. This causes G<sub>2</sub>/M phase arrest in SN20 but G<sub>1</sub>/S phase arrest in LD10 under Cd stress. G<sub>2</sub>/M phase arrest in SN20 allows DNA 915 replication leading to cell volume enlargement and some cell proliferation with 916 post-replication repair, but G<sub>1</sub>/S phase arrest in LD10 does not. This explains 917 the different Cd-induced root growth repression in SN20 and LD10. This 918

hypothesis was tested by knocking down *MSH2* or *MSH6* from SN20, and by
knocking down *MLH1* from LD10 increasing G<sub>1</sub>/S phase arrest through blocking
the MRN complex-to-ATM signaling.

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Figure 10. Multiple effects of MMR system on Cd tolerance in soybean. MSH2 923 and MSH6 forming MutSa regulate the cell cycle by activating the G<sub>2</sub>/M 924 checkpoint, leading to cell cycle arrest, when they recognize Cd-induced DNA 925 damage. Furthermore, MutSα can recruit MutL and BRCA1/Rad51 to trigger 926 MMR and HR mediated repair. When MSH2 or MSH6 was knocked down, HR 927 repair would be repressed causing increased SSBs and DSBs. Knocking down 928 MLH1 would suppress MMR, but improve HR repair because of reduced G<sub>1</sub>/S 929 arrest leading to enhanced post-replication repair in increased G<sub>2</sub> phase. 930